



**THE DATASHEET OF
SD233N45S50PSC**



FAST RECOVERY DIODES

Stud Version

Features

- High power FAST recovery diode series
- 4.5 μ s recovery time
- High voltage ratings up to 4500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Compression bonded encapsulation
- Stud version case style B-8
- Maximum junction temperature 125°C
- RoHS Compliant

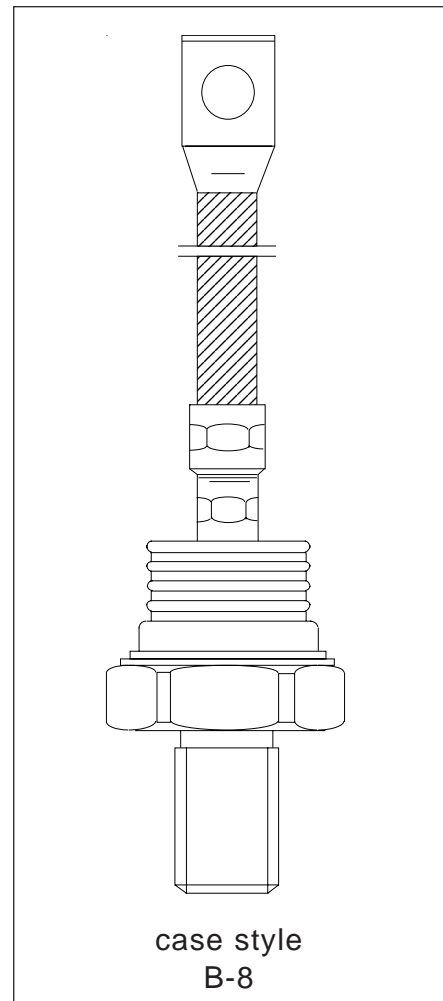
235A

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

Major Ratings and Characteristics

Parameters	SD233N/R	Units
$I_{F(AV)}$	235	A
@ T_C	60	°C
$I_{F(RMS)}$	370	A
I_{FSM} @ 50Hz	5500	A
@ 60Hz	5760	A
I^2t @ 50Hz	151	KA ² s
@ 60Hz	138	KA ² s
V_{RRM} range	3000 to 4500	V
t_{rr}	4.5	μ s
@ T_J	125	°C
T_J	-40 to 125	°C



ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V _{RRM} max. repetitive peak and off-state voltage V	V _{RSM} , maximum non-repetitive peak voltage V	I _{RRM} max. T _J = 125°C mA
SD233N/R	30	3000	3100	50
	36	3600	3700	
	40	4000	4100	
	45	4500	4600	

Forward Conduction

Parameter	SD233N/R	Units	Conditions		
I _{F(AV)} Max. average forward current @ Case temperature	235	A	180° conduction, half sine wave.		
	60	°C			
I _{F(RMS)} Max. RMS current	370	A	@ 45°C case temperature		
I _{FSM} Max. peak, one-cycle non-repetitive forward current	5500	A	t = 10ms No voltage		
	5760		t = 8.3ms reappplied		
	4630		t = 10ms 50% V _{RRM}		
	4840		t = 8.3ms reappplied		
I ² t Maximum I ² t for fusing	151	KA ² s	t = 10ms No voltage		
	138		t = 8.3ms reappplied		
	107		t = 10ms 50% V _{RRM}		
	98		t = 8.3ms reappplied		
I ² √t Maximum I ² √t for fusing	1510	KA ² √s	t = 0.1 to 10ms, no voltage reappplied		
	V _{F(TO)1} Low level of threshold voltage		1.56	V	(16.7% x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J max.
	V _{F(TO)2} High level of threshold voltage		1.68		(I > π x I _{F(AV)}), T _J = T _J max.
	r _{f1} Low level of forward slope resistance		1.64	mΩ	(16.7% x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J max.
r _{f2} High level of forward slope resistance	1.53	(I > π x I _{F(AV)}), T _J = T _J max.			
V _{FM} Max. forward voltage	3.2	V	I _{pk} = 1000A, T _J = 125°C, t _p = 400 μs square pulse		

Recovery Characteristics

Code	T _J = 25°C typical t _{rr} @ 25% I _{RRM} (μs)	Testconditions			Max. values @ T _J = 125°C			
		I _{pk} Square Pulse (A)	di/dt (*) (A/μs)	V _r (V)	t _{rr} @ 25% I _{RRM} (μs)	Q _{rr} (μC)	I _{rr} (A)	
S50	5.0	1000	100	-50	4.5	680	240	

(*) di/dt = 25A/μs @ T_J = 25°C

Thermal and Mechanical Specification

Parameter	SD233N/R	Units	Conditions
T _J Max. operating temperature range	-40 to 125	°C	
T _{stg} Max. storage temperature range	-40 to 150		
R _{thJC} Max. thermal resistance, junction to case	0.1	K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.04		Mounting surface, smooth, flat and greased
T Mounting torque ± 10%	50	N m	Not lubricated threads
wt Approximate weight	454	g	
Case style	B-8		See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.010	0.008	K/W	T _J = T _J max.
120°	0.013	0.014		
90°	0.017	0.018		
60°	0.025	0.026		
30°	0.041	0.042		

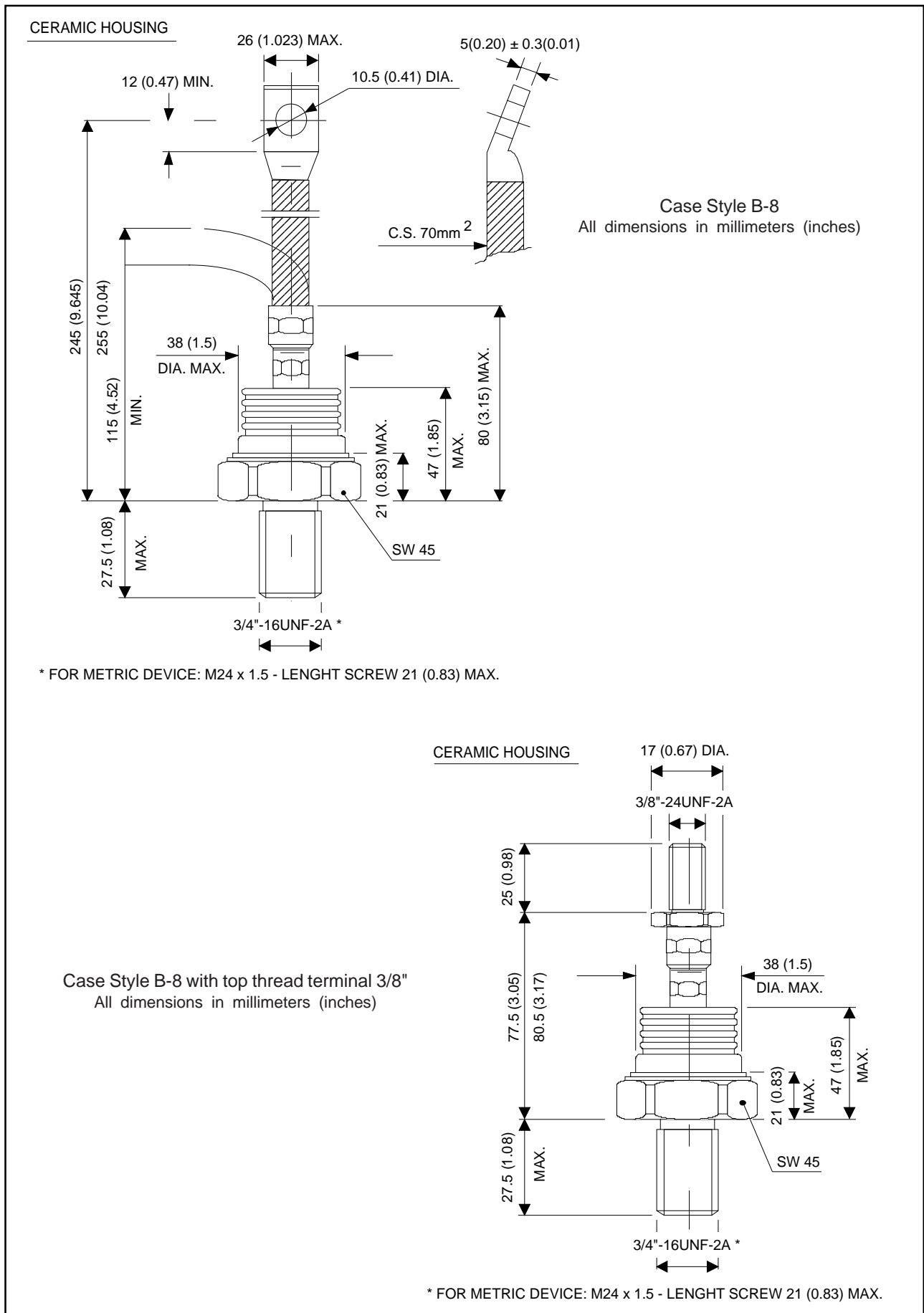
Ordering Information Table

Device Code

SD	23	3	N	45	S50	P	S	C
①	②	③	④	⑤	⑥	⑦	⑧	⑨

- 1** - Diode
- 2** - Essential part number
- 3** - 3 = Fast recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)
- 6** - t_{rr} code (see Recovery Characteristics table)
- 7** - P = Stud base B-8 3/4" 16UNF-2A
M = Stud base B-8 M24 X 1.5
- 8** - S = Isolated lead with silicone sleeve
(Red = Reverse Polarity; Blue = Normal Polarity)
T = Threaded Top Terminal 3/8" 24UNF-2A
None = Not isolated lead
- 9** - C = Ceramic housing

Outlines Table



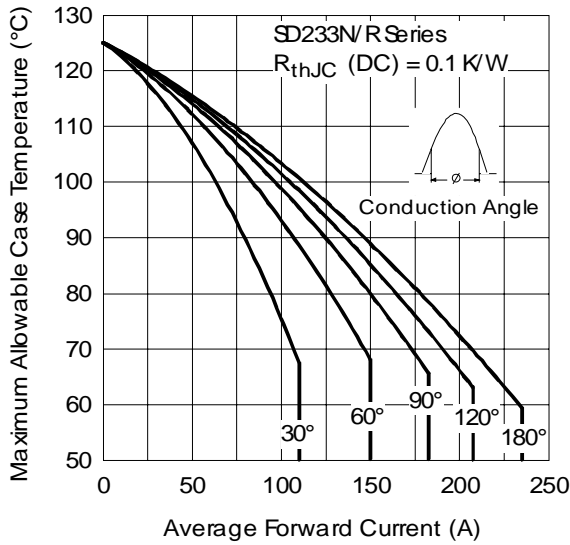


Fig. 1 - Current Ratings Characteristics

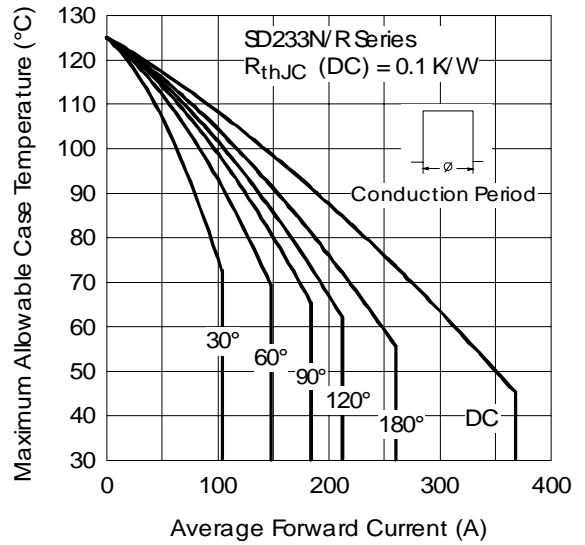


Fig. 2 - Current Ratings Characteristics

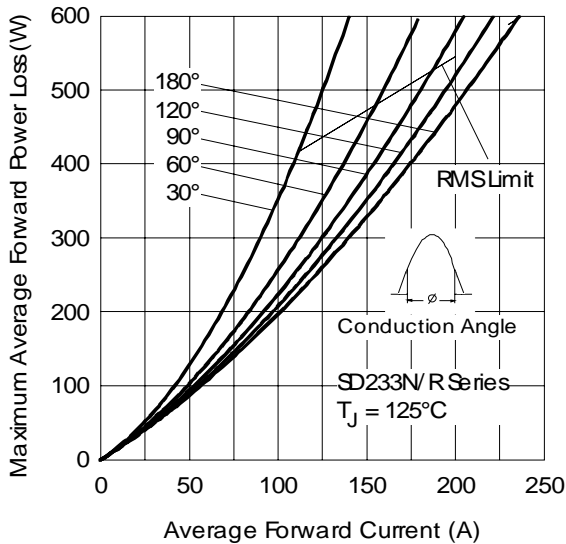


Fig. 3 - Forward Power Loss Characteristics

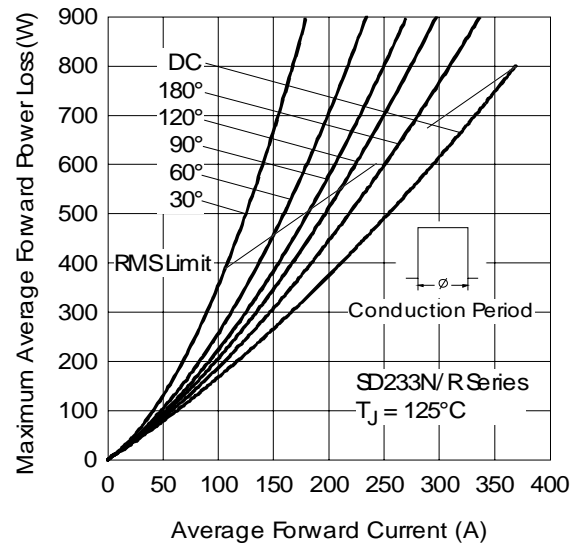


Fig. 4 - Forward Power Loss Characteristics

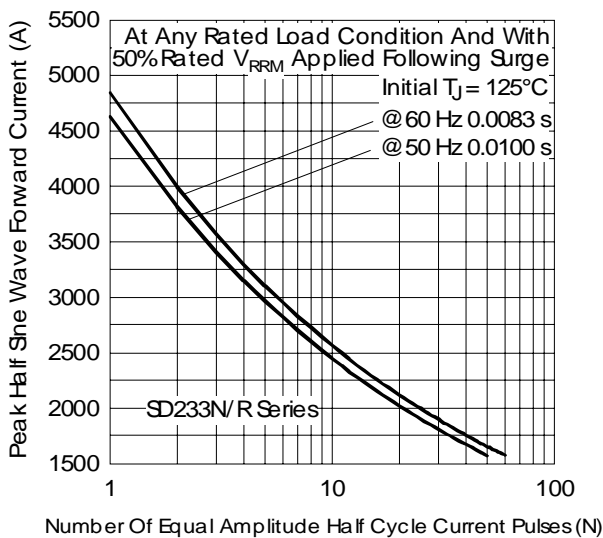


Fig. 5 - Maximum Non-repetitive Surge Current

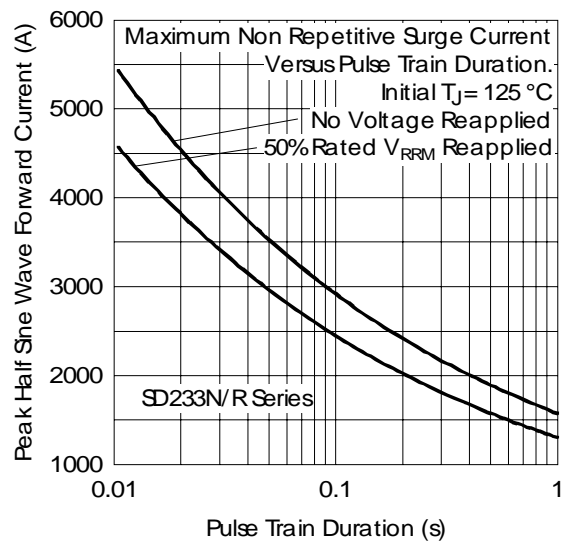


Fig. 6 - Maximum Non-repetitive Surge Current

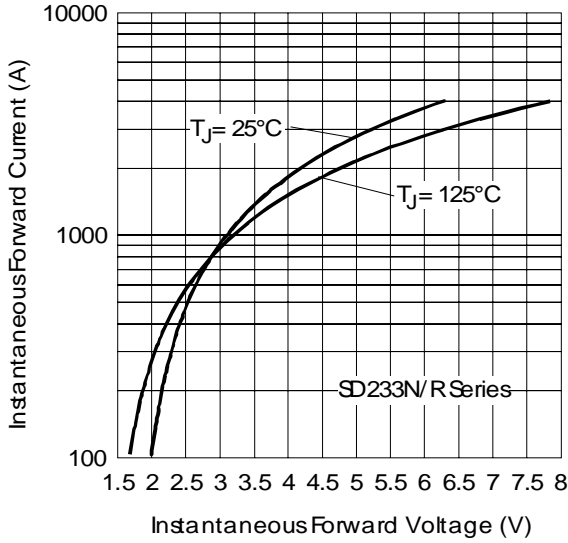


Fig. 7 - Forward Voltage Drop Characteristics

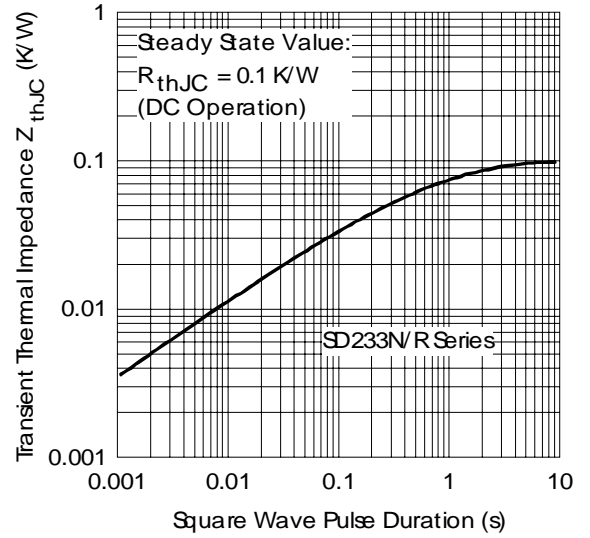


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

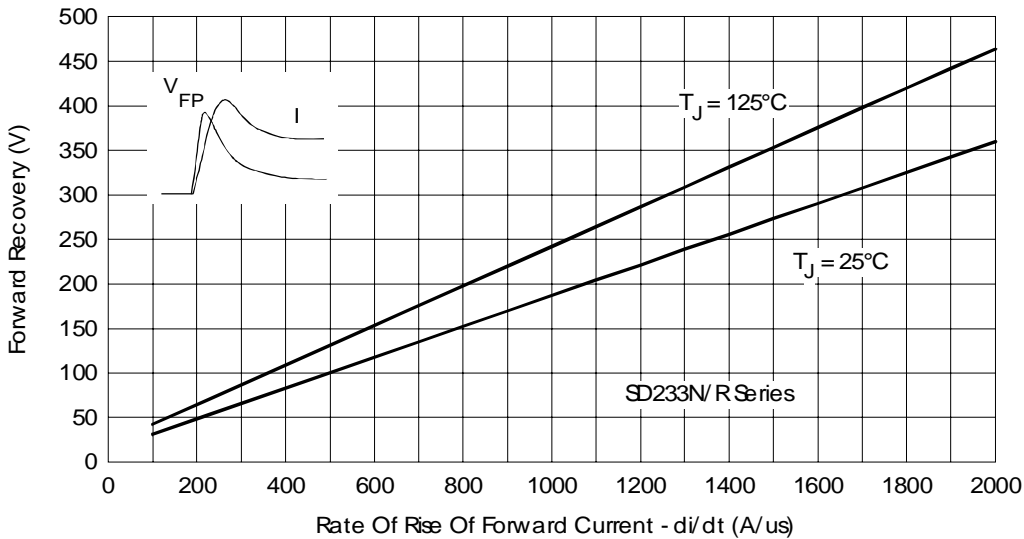


Fig. 9 - Typical Forward Recovery Characteristics

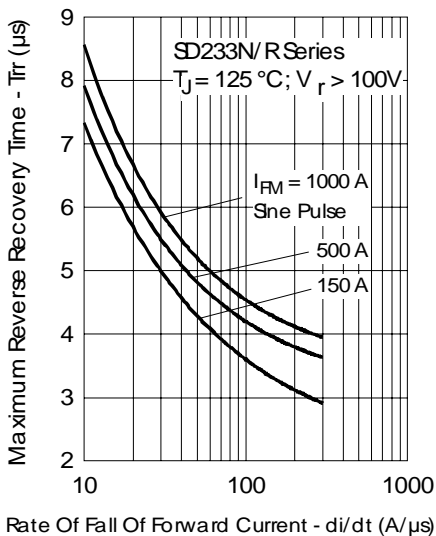


Fig. 10 - Recovery Time Characteristics

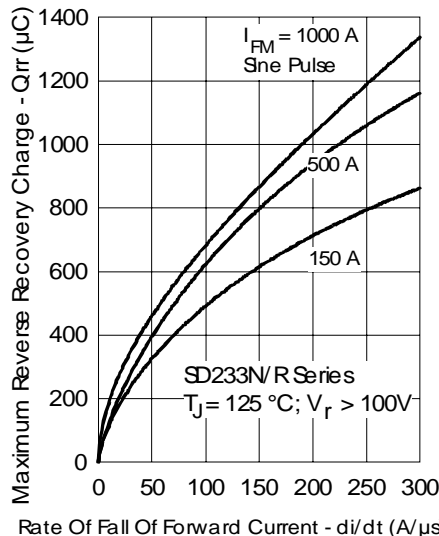


Fig. 11 - Recovery Charge Characteristics

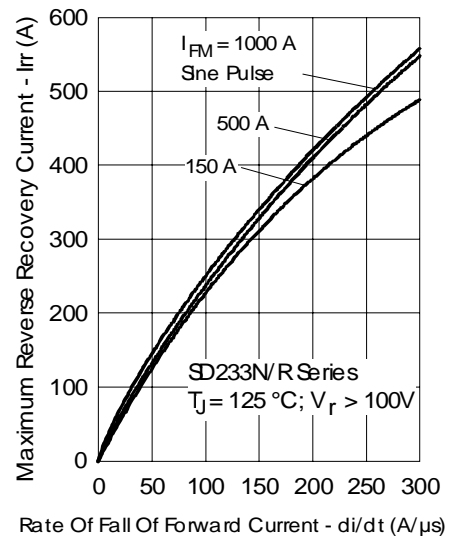


Fig. 12 - Recovery Current Characteristics

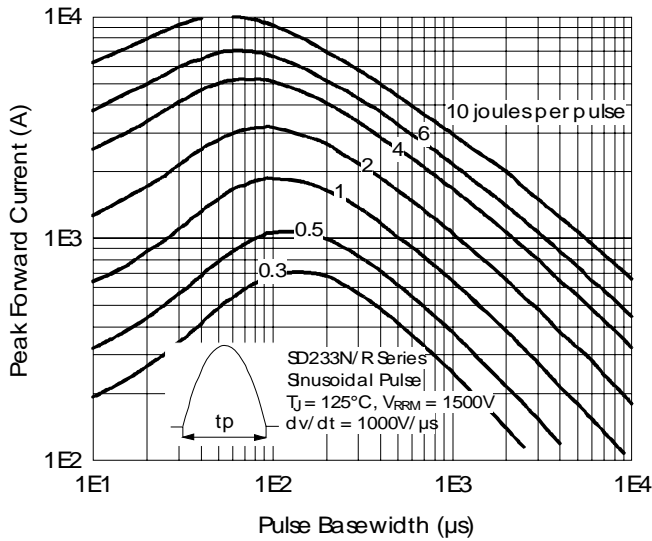


Fig. 13 - Maximum Total Energy Loss Per Pulse Characteristics

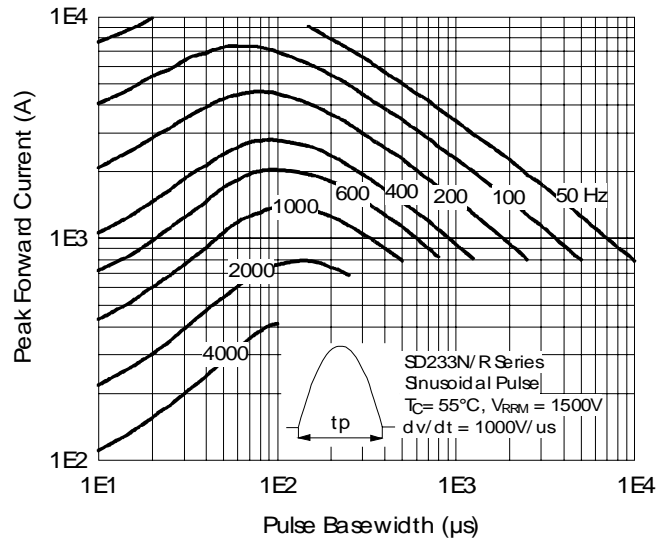


Fig. 14 - Frequency Characteristics

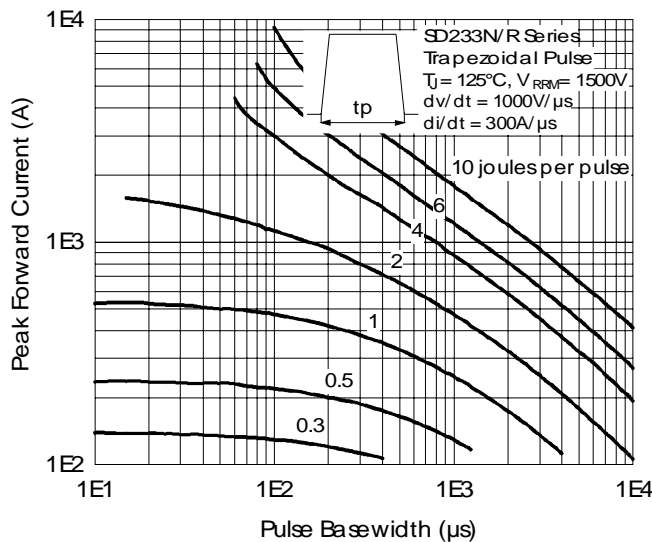


Fig. 15 - Maximum Total Energy Loss Per Pulse Characteristics

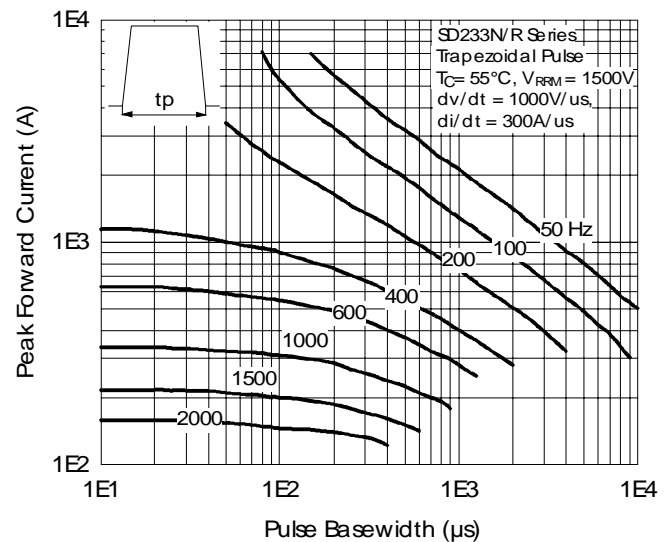


Fig. 16 - Frequency Characteristics

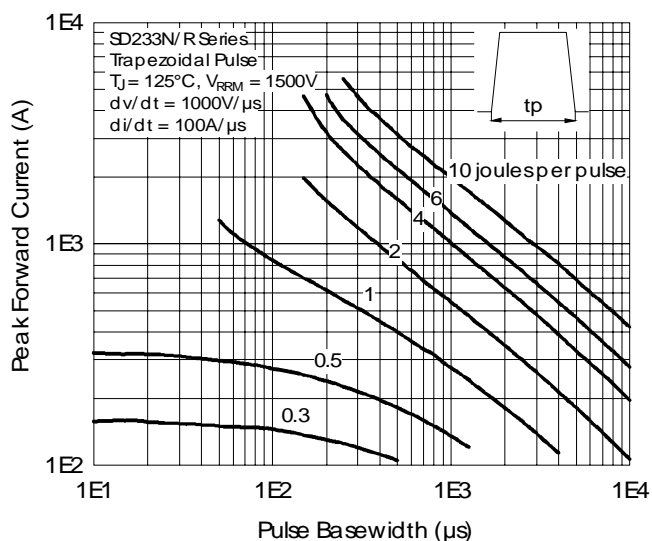


Fig. 17 - Maximum Total Energy Loss Per Pulse Characteristics

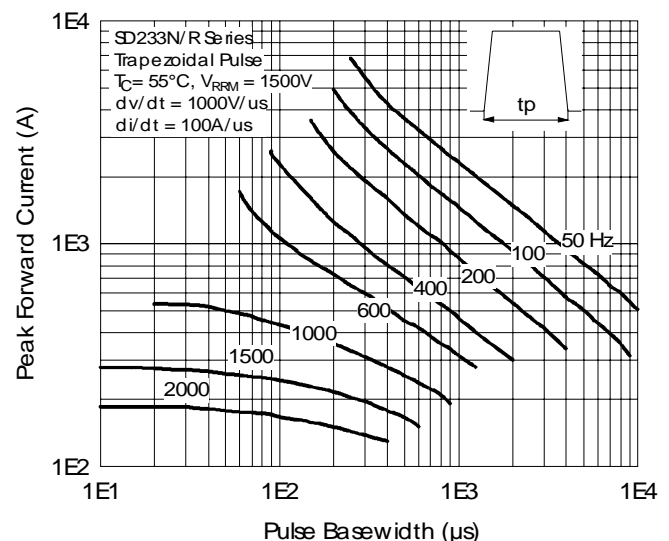


Fig. 18 - Frequency Characteristics

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.



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